

We claim:

1 1. A method of applying a thin film coating to a
2 substrate, comprising the steps of:

3 (a) mounting a substrate to be coated on a substrate
4 holder in an evacuatable chamber and so that said substrate is
5 spacedly juxtaposed with a crucible containing a component of a
6 coating to be applied to said substrate;

7 (b) evacuating said chamber;

8 (c) positioning a shutter between said crucible and
9 said substrate and heating said component in said crucible with a
10 high energy beam;

11 (d) admitting a gas mixture to said chamber containing
12 at least one gas reactive with said component to form said
13 coating;

14 (e) connecting said substrate holder to a radio
15 frequency or pulsed direct current source so that said substrate
16 holder is poled cathodic and a plasma is formed at least around
17 said substrate to create a self bias of several hundreds of volts
18 on said substrate holder and a surface of said substrate is
19 bombarded with particles from the plasma;

20 (f) withdrawing said shutter from its position between
21 said crucible and said substrate, bombarding said component with

23 and depositing a reaction product of said component and said at
 24 least one gas on said substrate; and
 25 (g) controlling the ionization of said component so
 26 that said self bias is reduced by at least 50%.

1 2. The method defined in claim 1 wherein said self
 2 bias and said plasma are produced by connecting said substrate
 3 holder to a radio frequency source.

1 3. The method defined in claim 2 wherein the
 2 deposition of said coating is monitored and the coating is
 3 terminated when a predetermined thickness of the coating is
 4 reached.

1 4. The method defined in claim 1 wherein said thin
 2 film coating is an optical coating.

1 5. The method defined in claim 1, further comprising
 2 the step of depositing a reaction product of a component from
 3 another crucible and said at least one gas on said substrate
 4 following the deposition of said coating thereon.

1 6. The method defined in claim 1 wherein said
 2 component is heated in said crucible with a high energy electron
 3 beam from an electron beam gun.

1 7. The method defined in claim 6, further comprising

1 8. An apparatus for applying a thin film coating to a
2 substrate comprising:
3 a vacuum chamber connectable to a pump adapted to
4 evacuate said chamber;
5 at least one crucible in said chamber;
6 a substrate holder in said chamber receiving a
7 substrate to be coated and juxtaposed with said crucible;
8 a mechanical shutter in said chamber interposable
9 between said crucible and said substrate;
10 a high-energy source for heating a component of a
11 coating to be deposited upon said substrate in said crucible;
12 a radio frequency or pulsed direct current source
13 connectable to said substrate holder for producing a plasma
14 around said substrate and imparting a self-bias to said substrate
15 holder poling said substrate holder cathodic;
16 means for feeding a gas mixture to said chamber
17 including at least one gas reactive with said component to form a
18 coating on said substrate; and
19 a low energy electron source for ionizing said
20 component to reduce said self-bias and deposit a reaction product
21 of said component and said at least one gas on said substrate,
22 said shutter being movable from one said crucible and said
23 substrate to permit ionization of said component.

1 9. The apparatus defined in claim 8 wherein said
2 substrate holder is mounted for rotation in said chamber.

1 10. The apparatus defined in claim 9 wherein said
said source said substrate holder.

1 11. The apparatus defined in claim 10, further
2 comprising an instrument for measuring the thickness of said
3 coating on said substrate for controlling the deposition of said
4 reaction product on said substrate.

1 12. The apparatus defined in claim 11 wherein said
2 crucible is electrically heated.

1 13. The apparatus defined in claim 11 wherein said
2 component is heated in said crucible by sputtering.

1 14. The apparatus defined in claim 11 wherein said
2 source is a radio frequency source.

1 15. The apparatus defined in claim 11 wherein said
2 crucible is rotatable in said chamber.

1 16. The apparatus defined in claim 11, further
2 comprising another crucible containing a respective component
3 capable of forming a reaction product which can be deposited on
4 said coating.

1 17. The apparatus defined in claim 11 wherein said
2 component is heated in part by an electron beam gun.

1 18. The apparatus defined in claim 17, further
2 comprising another electron beam gun in said chamber for heating

1 19. A method of applying a thin film coating to a
2 substrate, comprising the steps of:

3 (a) mounting a substrate to be coated on a substrate
4 holder in an evacuable chamber and so that said substrate is
5 spacedly juxtaposed with a crucible containing a component of a
6 coating to be applied to said substrate;

7 (b) evacuating said chamber;

8 (c) positioning a shutter between said crucible and
9 said substrate and heating said component in said crucible with a
10 high energy beam;

11 (d) admitting a gas mixture to said chamber;

12 (e) connecting said substrate holder to a radio
13 frequency or pulsed direct current source so that said substrate
14 holder is poled cathodic and a plasma is formed at least around
15 said substrate to create a self bias of several hundreds of volts
16 on said substrate holder and a surface of said substrate is
17 bombarded with particles from the plasma;

18 (f) withdrawing said shutter from its position between
19 said crucible and said substrate, bombarding said component with
20 low energy electrons to ionize said component at least in part
21 and depositing said component and said at least one gas on said
22 substrate; and

23 (g) controlling the ionization of said component so
24 that said self bias is reduced by at least 50%.